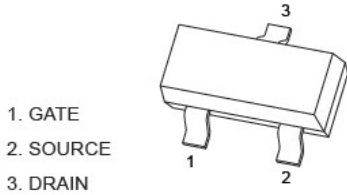
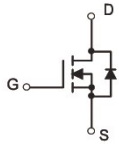


V(BR)DSS	RDS(ON)MAX	ID
60V	5Ω@10V	115mA
	7Ω@5V	

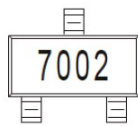
SOT-23



Equivalent Circuit



MARKING



特征 Features

- High density cell design for low $R_{DS(ON)}$.
- Voltage controlled small signal switch.
- Rugged and reliable.
- High saturation current capability.
- Load Switch for Portable Devices.
- DC/DC Converter.

机械数据 Mechanical Data

- 封装: SOT-23 封装 SOT-23 Small Outline Plastic Package.
- 环氧树脂 UL 易燃等级 Epoxy UL: 94V-0.
- 安装位置: 任意 Mounting Position: Any.

极限值和温度特性($T_A = 25^\circ\text{C}$ 除非另有规定)

Maximum Ratings & Thermal Characteristics (Ratings at 25°C ambient temperature unless otherwise specified.)

参数 Parameters	符号 Symbol	数值 Value	单位 Unit
Drain-Source Voltage	V_{DS}	60	V
Gate-Source Voltage	V_{GS}	± 20	V
Continuous Drain Current	I_D	115	mA
Power Dissipation	P_D	225	mW
Junction Temperature	T_j	150	$^\circ\text{C}$
Storage Temperature	T_{stg}	-50-+150	$^\circ\text{C}$
Thermal Resistance From Junction to Ambient	$R_{\theta JA}$	556	$^\circ\text{C/W}$

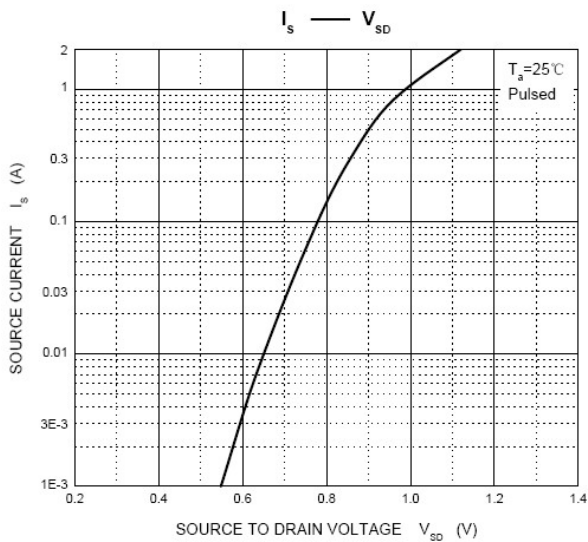
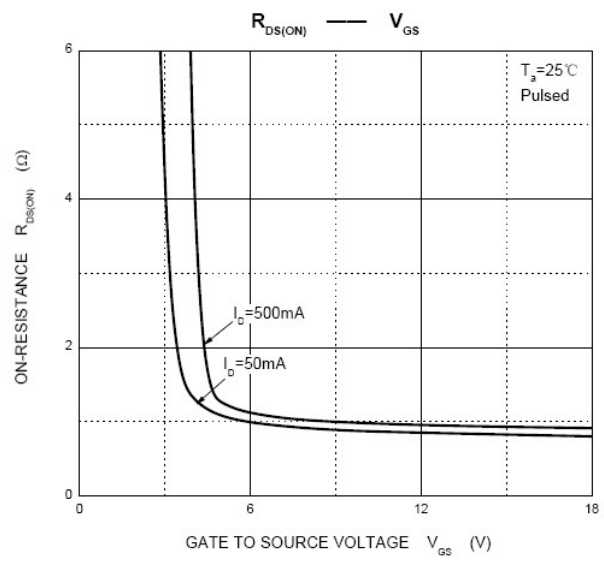
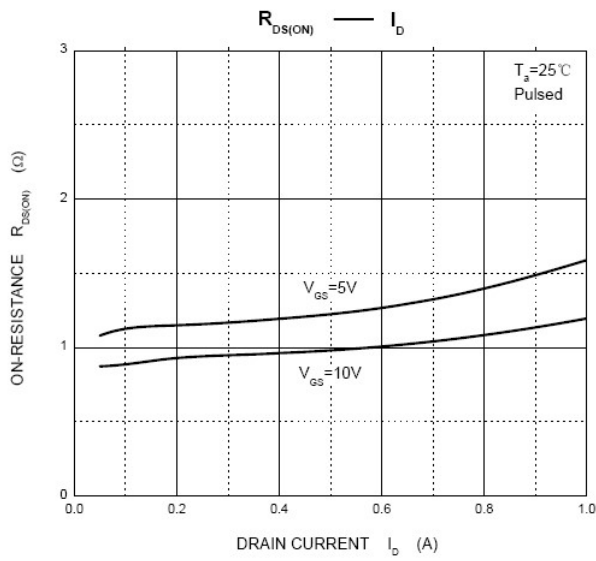
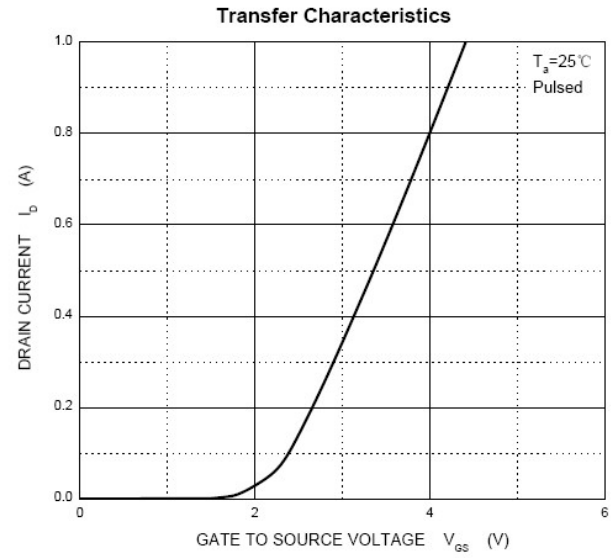
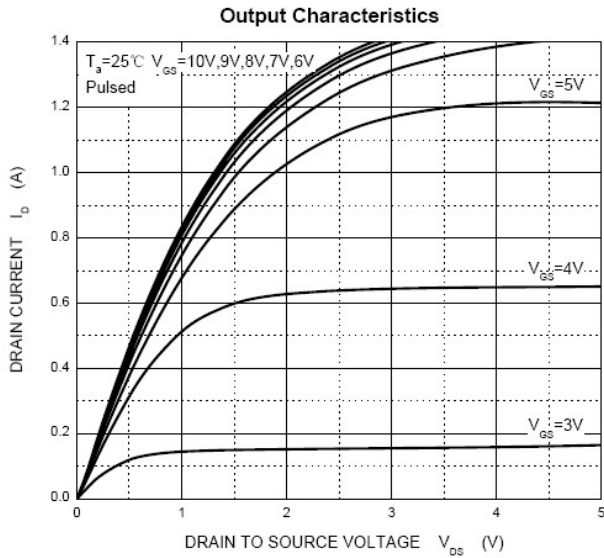
电特性 ($T_A = 25^\circ\text{C}$ 除非另有规定)

Electrical Characteristics (Ratings at 25°C ambient temperature unless otherwise specified.)

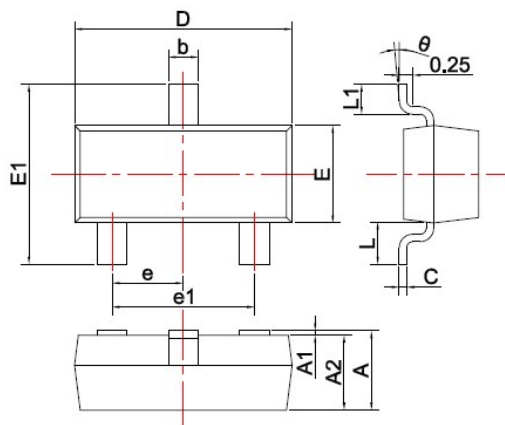
参数 Parameter	符号 Symbols	测试条件 Test Condition	界限 Limits		单位 Unit
			Min	Max	
Drain-Source Breakdown Voltage	V(BR)DSS	VGS=0V, ID=250uA	60		V
Gate-Threshold voltage	Vth(GS)	VDS=VGS, ID=250uA	1	2.5	V
Gate-body Leakage	IGSS	VDS=0V, VGS=±20V		±80	nA
Zero Gate Voltage Drain current	IDSS	VDS=60V, VGS=0V		80	nA
On-state Drain current	ID(ON)	VGS=10V, VDS=7V	500		mA
Drain-Source On-Resistance	RDS(ON)	VGS=10V, ID=500mA		5	Ω
		VGS=5V, IC=50mA		7	
Forward Trans conductance	gfs	VDS=10V, ID=200mA	80		ms
Drain-source on-voltage	VDS(ON)	VGS=10V, ID=500mA		3.75	V
		VGS=5V, ID=50mA		0.375	V
Diode Forward voltage	VSD	IS=115mA, VGS=0V	0.55	1.20	V
Input capacitance*	Ciss	VDS=25V, VGS=0V,f=1MHz		50	pF
Output capacitance*	Coss			25	
Reverse Transfer capacitance*	Crss			5	
SWITCHING TIME					
Turn-on Time*	td(on)	VDD=25V, RL=50Ω, ID=500mA, VGEN=10V, RG=25Ω		20	ns
Turn-off Time*	td(off)			40	

* These parameters have on way to verify.

Typical characteristics



SOT-23 PACKAGE OUTLINE Plastic surface mounted package

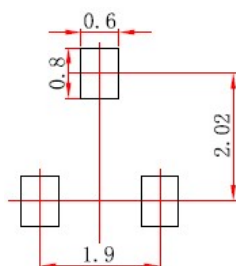


SYMBOL	DIMENSIONS	
	MIN.	MAX.
A	0.900	1.150
A1	0.000	0.100
A2	0.900	1.050
b	0.300	0.500
c	0.080	0.150
D	2.800	3.000
E	1.200	1.400
E1	2.250	2.550
e	0.950TYP	
e1	1.800	2.000
L	0.550REF	
L1	0.300	0.500
θ	0°	8°

Unit: mm

焊盘设计参考Precautions: PCB Design

Recommended land dimensions for SOT-23 diode. Electrode patterns for PCBs



Note:

1. Controlling dimension: in millimeters.
2. General tolerance: $\pm 0.05\text{mm}$.
3. The pad layout is for reference purposes only.

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